

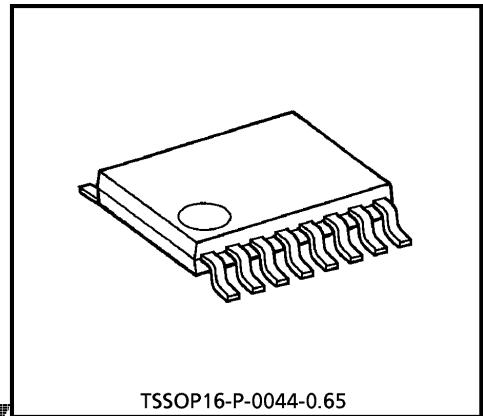
TC74VCX157FT**LOW-VOLTAGE QUAD 2-CHANNEL MULTIPLEXER
WITH 3.6 V TOLERANT INPUTS AND OUTPUTS**

The TC74VCX157FT is a high performance CMOS MULTIPLEXER. Designed for use in 1.8, 2.5 or 3.3 Volt systems, it achieves high speed operation while maintaining the CMOS low power dissipation. It is also designed with over voltage tolerant inputs and outputs up to 3.6 V.

It consists of four 2-input digital multiplexers with common select and strobe inputs.

When the STROBE input is held "H" level, selection of data is inhibited and all the outputs become "L" level. The SELECT decoding determines whether the A or B inputs get routed to their corresponding Y outputs.

All inputs are equipped with protection circuits against static discharge.



TSSOP16-P-0044-0.65

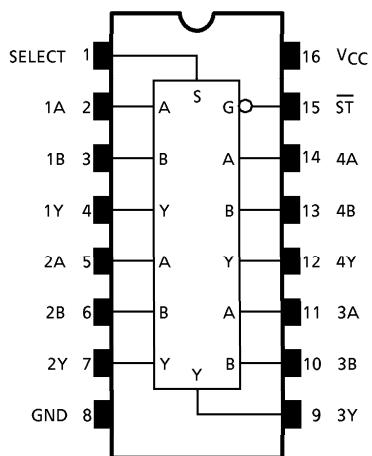
Weight : 0.06 g (Typ.)

PRELIMINARY**FEATURES**

- Low Voltage Operation : $V_{CC} = 1.8\sim 3.6$ V
- High Speed Operation : $t_{pd} = 2.5$ ns (max) at $V_{CC} = 3.0\sim 3.6$ V
 $t_{pd} = 3.0$ ns (max) at $V_{CC} = 2.3\sim 2.7$ V
 $t_{pd} = 5.0$ ns (max) at $V_{CC} = 1.8$ V
- Output Current : $I_{OH}/I_{OL} = \pm 24$ mA (min) at $V_{CC} = 3.0$ V
 $I_{OH}/I_{OL} = \pm 18$ mA (min) at $V_{CC} = 2.3$ V
 $I_{OH}/I_{OL} = \pm 6$ mA (min) at $V_{CC} = 1.8$ V
- Latch-up Performance : ± 300 mA
- ESD Performance : Human Body Model $> \pm 2000$ V
Machine Model $> \pm 200$ V
- Package : TSSOP
(Thin Shrink Small Outline Package)
- Power Down Protection is provided on all inputs and outputs.

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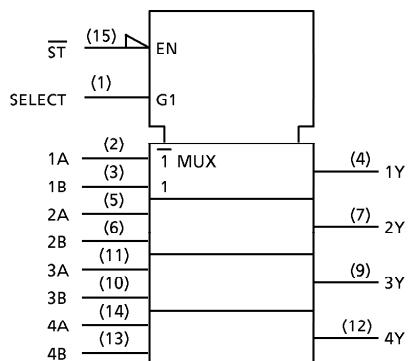
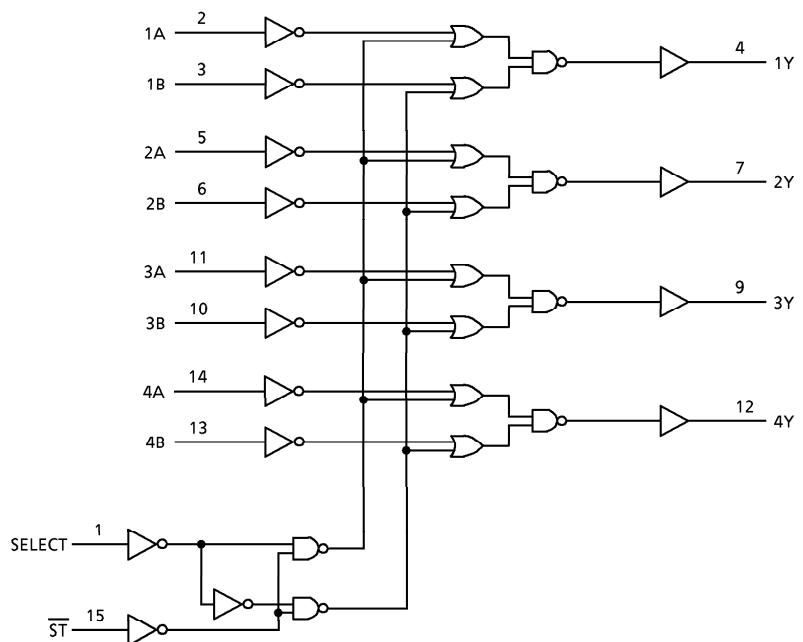
(TOP VIEW)

TRUTH TABLE

		INPUTS		OUTPUTS
\bar{ST}	SELECT	A	B	Y
H	X	X	X	L
L	L	L	X	L
L	L	H	X	H
L	H	X	L	L
L	H	X	H	H

X : Don't Care

PRELIMINARY

IEC LOGIC SYMBOL**SYSTEM DIAGRAM**

MAXIMUM RATINGS

PARAMETER	SYMBOL	RATING	UNIT
Power Supply Voltage	V_{CC}	- 0.5~4.6	V
DC Input Voltage	V_{IN}	- 0.5~4.6	V
DC Output Voltage	V_{OUT}	- 0.5~4.6 (Note 1)	V
		- 0.5~ V_{CC} + 0.5 (Note 2)	
Input Diode Current	I_{IK}	- 50	mA
Output Diode Current	I_{OK}	\pm 50 (Note 3)	mA
DC Output Current	I_{OUT}	\pm 50	mA
Power Dissipation	P_D	180	mW
DC V_{CC} / Ground Current	I_{CC} / I_{GND}	\pm 100	mA
Storage Temperature	T_{stg}	- 65~150	°C

(Note 1): $V_{CC} = 0$ V(Note 2): High or Low State. I_{OUT} absolute maximum rating must be observed.(Note 3): $V_{OUT} < GND$, $V_{OUT} > V_{CC}$ **PRELIMINARY****RECOMMENDED OPERATING RANGE**

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	V_{CC}	1.8~3.6	V
		1.2~3.6 (Note 4)	
Input Voltage	V_{IN}	- 0.3~3.6	V
Output Voltage	V_{OUT}	0~3.6 (Note 5)	V
		0~ V_{CC} (Note 6)	
Output Current	I_{OH} / I_{OL}	\pm 24 (Note 7)	mA
		\pm 18 (Note 8)	
		\pm 6 (Note 9)	
Operating Temperature	T_{opr}	- 40~85	°C
Input Rise And Fall Time	dt / dv	0~10 (Note 10)	ns/V

(Note 4): Data Retention Only

(Note 5): $V_{CC} = 0$ V

(Note 6): High or Low State

(Note 7): $V_{CC} = 3.0$ ~3.6 V(Note 8): $V_{CC} = 2.3$ ~2.7 V(Note 9): $V_{CC} = 1.8$ V(Note 10): $V_{IN} = 0.8$ ~2.0 V, $V_{CC} = 3.0$ V

ELECTRICAL CHARACTERISTICSDC Characteristics ($T_a = -40\text{--}85^\circ\text{C}$, $2.7\text{ V} < V_{CC} \leq 3.6\text{ V}$)

PARAMETER		SYMBOL	TEST CONDITION		$V_{CC}\text{ (V)}$	Min	Max	UNIT	
Input Voltage	"H" Level	V_{IH}				2.7~3.6	2.0	—	
	"L" Level	V_{IL}				2.7~3.6	—	0.8	
Output Voltage	"H" Level	V_{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -100\text{ }\mu\text{A}$	2.7~3.6	$V_{CC} - 0.2$	—	V	
				$I_{OH} = -12\text{ mA}$	2.7	2.2	—		
				$I_{OH} = -18\text{ mA}$	3.0	2.4	—		
				$I_{OH} = -24\text{ mA}$	3.0	2.2	—		
	"L" Level	V_{OL}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 100\text{ }\mu\text{A}$	2.7~3.6	—	0.2	V	
				$I_{OL} = 12\text{ mA}$	2.7	—	0.4		
				$I_{OL} = 18\text{ mA}$	3.0	—	0.4		
				$I_{OL} = 24\text{ mA}$	3.0	—	0.55		
Input Leakage Current		I_{IN}	$V_{IN} = 0\text{--}3.6\text{ V}$		2.7~3.6	—	± 5.0	μA	
Power Off Leakage Current		I_{OFF}	$V_{IN}, V_{OUT} = 0\text{--}3.6\text{ V}$		0	—	10.0	μA	
Quiescent Supply Current		I_{CC}	$V_{IN} = V_{CC}$ or GND		2.7~3.6	—	20.0	μA	
Increase In I_{CC} Per Input		ΔI_{CC}	$V_{IH} = V_{CC} - 0.6\text{ V}$		2.7~3.6	—	750		

PRELIMINARY**ELECTRICAL CHARACTERISTICS**DC Characteristics ($T_a = -40\text{--}85^\circ\text{C}$, $2.3\text{ V} \leq V_{CC} \leq 2.7\text{ V}$)

PARAMETER		SYMBOL	TEST CONDITION		$V_{CC}\text{ (V)}$	Min	Max	UNIT	
Input Voltage	"H" Level	V_{IH}				2.3~2.7	1.6	—	
	"L" Level	V_{IL}				2.3~2.7	—	0.7	
Output Voltage	"H" Level	V_{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -100\text{ }\mu\text{A}$	2.3~2.7	$V_{CC} - 0.2$	—	V	
				$I_{OH} = -6\text{ mA}$	2.3	2.0	—		
				$I_{OH} = -12\text{ mA}$	2.3	1.8	—		
				$I_{OH} = -18\text{ mA}$	2.3	1.7	—		
	"L" Level	V_{OL}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 100\text{ }\mu\text{A}$	2.3~2.7	—	0.2	V	
				$I_{OL} = 12\text{ mA}$	2.3	—	0.4		
				$I_{OL} = 18\text{ mA}$	2.3	—	0.6		
				$I_{OL} = 24\text{ mA}$	2.3	—	0.8		
Input Leakage Current		I_{IN}	$V_{IN} = 0\text{--}3.6\text{ V}$		2.3~2.7	—	± 5.0	μA	
Power Off Leakage Current		I_{OFF}	$V_{IN}, V_{OUT} = 0\text{--}3.6\text{ V}$		0	—	10.0	μA	
Quiescent Supply Current		I_{CC}	$V_{IN} = V_{CC}$ or GND		2.3~2.7	—	20.0	μA	
			$V_{CC} \leq V_{IN} \leq 3.6\text{ V}$		2.3~2.7	—	± 20.0		

ELECTRICAL CHARACTERISTICSDC Characteristics ($T_a = -40\text{--}85^\circ\text{C}$, $1.8\text{ V} \leq V_{CC} < 2.3\text{ V}$)

PARAMETER		SYMBOL	TEST CONDITION		V_{CC} (V)	Min	Max	UNIT	
Input Voltage	"H" Level	V_{IH}			1.8~2.3	$0.7 \times V_{CC}$	—	V	
	"L" Level	V_{IL}			1.8~2.3	—	$0.2 \times V_{CC}$		
Output Voltage	"H" Level	V_{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -100\text{ }\mu\text{A}$	1.8	$V_{CC} - 0.2$	—	V	
				$I_{OH} = -6\text{ mA}$	1.8	1.4	—		
	"L" Level	V_{OL}	$V_N = V_{IH}$ or V_{IL}	$I_{OL} = 100\text{ }\mu\text{A}$	1.8	—	0.2		
				$I_{OL} = 6\text{ mA}$	1.8	—	0.3		
Input Leakage Current	I_{IN}	$V_{IN} = 0\text{--}3.6\text{ V}$		1.8		—	± 5.0	μA	
Power Off Leakage Current	I_{OFF}	$V_{IN}, V_{OUT} = 0\text{--}3.6\text{ V}$		0		—	10.0	μA	
Quiescent Supply Current	I_{CC}	$V_{IN} = V_{CC}$ or GND		1.8		—	20.0	μA	
		$V_{CC} \leq V_{IN} \leq 3.6\text{ V}$		1.8		—	± 20.0		

PRELIMINARYAC Characteristics ($T_a = -40\text{--}85^\circ\text{C}$, Input $t_r = t_f = 2.0\text{ ns}$, $C_L = 30\text{ pF}$, $R_L = 500\text{ }\Omega$)

PARAMETER		SYMBOL	TEST CONDITION		V_{CC} (V)	Min	Max	UNIT
Propagation Delay Time (A, B-Y)	t_{pLH} t_{pHL}	(Fig.1, 2)			1.8	1.0	5.0	ns
					2.5 ± 0.2	0.8	3.0	
					3.3 ± 0.3	0.6	2.5	
Propagation Delay Time (SELECT-Y)	t_{pLH} t_{pHL}	(Fig.1, 2)			1.8	1.0	6.5	ns
					2.5 ± 0.2	0.8	4.1	
					3.3 ± 0.3	0.6	3.5	
Propagation Delay Time (\overline{ST} -Y)	t_{pLH} t_{pHL}	(Fig.1, 2)			1.8	1.0	5.0	ns
					2.5 ± 0.2	0.8	3.8	
					3.3 ± 0.3	0.6	3.5	
Output To Output Skew	t_{osLH} t_{osHL}	(Note 11)			1.8	—	0.5	ns
					2.5 ± 0.2	—	0.5	
					3.3 ± 0.3	—	0.5	

For $C_L = 50\text{ pF}$, add approximately 300 ps to the AC maximum specification.

(Note 11): Parameter guaranteed by design.

$$(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)$$

Dynamic Switching Characteristics ($T_a = 25^\circ\text{C}$, Input $t_r = t_f = 2.0 \text{ ns}$, $C_L = 30 \text{ pF}$)

PARAMETER	SYMBOL	TEST CONDITION	$V_{CC} (\text{V})$	Typ.	UNIT
Quiet Output Maximum Dynamic V_{OL}	V_{OLP}	$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 12)	1.8	0.25	V
		$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 12)	2.5	0.6	
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 12)	3.3	0.8	
Quiet Output Minimum Dynamic V_{OL}	V_{OLV}	$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 12)	1.8	-0.25	V
		$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 12)	2.5	-0.6	
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 12)	3.3	-0.8	
Quiet Output Minimum Dynamic V_{OH}	V_{OHV}	$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 12)	1.8	1.5	V
		$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 12)	2.5	1.9	
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 12)	3.3	2.2	

(Note 12): Parameter guaranteed by design.

Capacitive Characteristics ($T_a = 25^\circ\text{C}$)

PARAMETER	SYMBOL	TEST CONDITION	$V_{CC} (\text{V})$	Typ.	UNIT
Input Capacitance	C_{IN}		1.8, 2.5, 3.3	6	pF
Power Dissipation Capacitance	C_{PD}	$f_{IN} = 10 \text{ MHz}$ (Note 13)	1.8, 2.5, 3.3	20	pF

(Note 13): C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

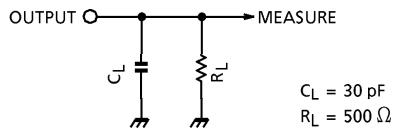
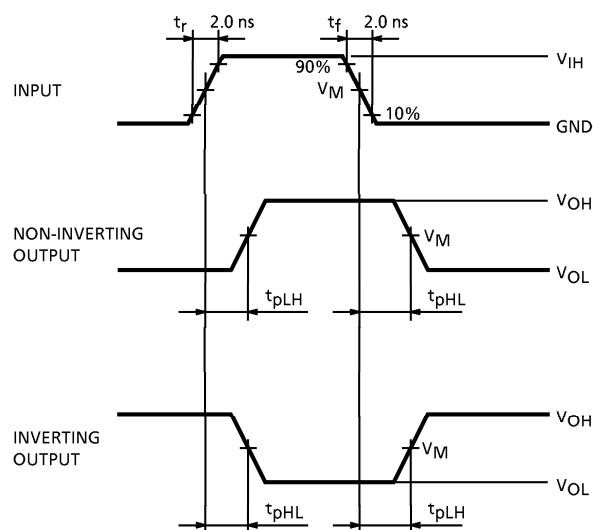
Average operating current can be obtained by the equation :

$$I_{CC(\text{opr.})} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

PRELIMINARY

TEST CIRCUIT

Fig.1

**AC WAVEFORM**Fig.2 t_{pLH} , t_{pHL} 

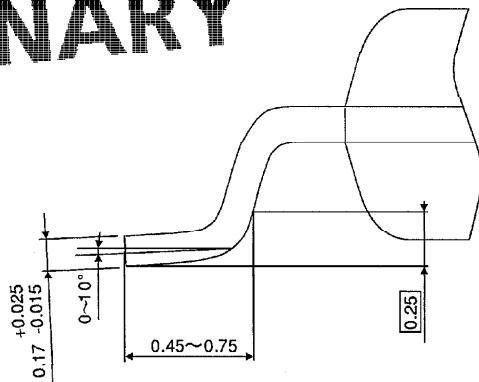
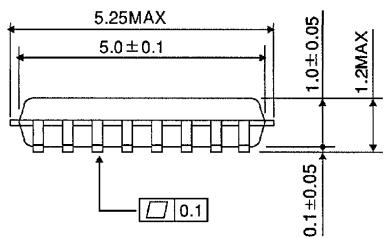
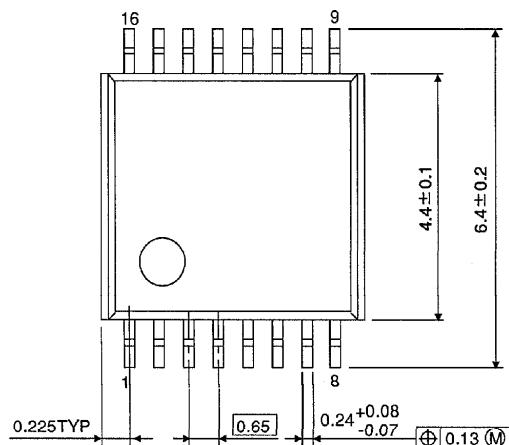
SYMBOL	V_{CC}		
	$3.3 \pm 0.3 \text{ V}$	$2.5 \pm 0.2 \text{ V}$	1.8 V
V_{IH}	2.7 V	V_{CC}	V_{CC}
V_M	1.5 V	$V_{CC}/2$	$V_{CC}/2$

PRELIMINARY

OUTLINE DRAWING

TSSOP16-P-0044-0.65

Unit : mm



Weight : 0.06 g (typ.)